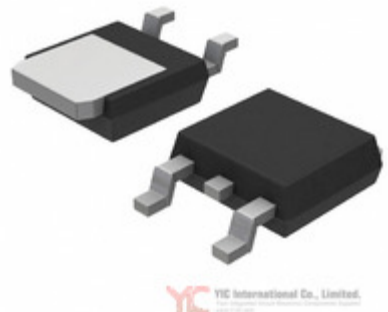

	<p><b>NTD12N10G</b></p>
	<p><b>Hersteller-Teilenummer:</b> NTD12N10G</p>
	<p><b>Hersteller / Marke:</b> AMI Semiconductor / ON Semiconductor</p>
	<p><b>Teil der Beschreibung:</b> MOSFET N-CH 100V 12A DPAK</p>
	<p><b>Datenblätter:</b>  <a href="#">NTD12N10G.pdf</a></p>
	<p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p>
	<p><b>Lagerzustand:</b> New original, 25000 pcs Stock Available.</p>
	<p><b>Liefern von:</b> Hong Kong</p>
<p>Image may be representation. See specs for product details.</p>	<p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>

Spezifikationen

Teilenummer	NTD12N10G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 100V 12A DPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	25000 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	DPAK
Verlustleistung (max)	1.28W (Ta), 56.6W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	100V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	12A (Ta)
Rds On (Max) @ Id, Vgs	165 mOhm @ 6A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	20nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	550pF @ 25V
Verpackung	Tube



















































NTD12N10G ist neu im Original. Suche NTD12N10G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTD12N10G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTD12N10G: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>NTD12N10-001</b> VB NTD12N10-001 VB</p>	 <p><b>NTD14N03R</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 2.5A DPAK</p>	 <p><b>NTD110N02RST4G</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 24V 100A DPAK</p>	 <p><b>NTD14N03</b> ON NTD14N03 ON</p>
 <p><b>NTD110N02RT4G</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 24V 12.5A DPAK</p>	 <p><b>NTD110N02RT4</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 24V 12.5A DPAK</p>	 <p><b>NTD14N03G</b> ON NTD14N03G ON</p>	 <p><b>NTD12N10T4G</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 12A DPAK</p>

heiße Teile

Mehr

 NTD110N02	 NTD110N02R	 NTD110N02R-001	 NTD110N02R-001G	 NTD110N02RG
 NTD110N02RT4G	 NTD12N10-001	 NTD12N10-1G	 NTD12N10T4	 NTD12N10T4G
 NTD14N03	 NTD14N03G	 NTD14N03R	 NTD14N03R-001	 NTD14N03R-1
 NTD14N03R-1G	 NTD14N03RG	 NTD14N03RT4	 NTD14N03RT4G	 NTD14N03RTCG
 NTD14N03T4G	 NTD15N06	 NTD15N06L	 NTD15N06LG	 NTD15N06LT4
 NTD15N06LT4G	 NTD15N06T4	 NTD15N06T4G	 NTD15N06VLT4	 NTD15N07
 NTD15N10	 NTD18N06-001	 NTD18N06-1G	 NTD18N06G	 NTD18N06L
 NTD18N06L-1G	 NTD18N06LG	 NTD18N06LT4G	 NTD18N06T4G	 NTD20N03
 NTD20N03G	 NTD20N03HL	 NTD20N03L27	 NTD20N03L27G	 NTD20N03L27T
 NTD20N03L27T4G	 NTD20N03L27T4G	 NTD20N03RT4G	 NTD20N06	 NTD20N06-001

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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